



DMN62D1LFD

Product Summary

BV _{DSS}	R _{DS(ON)}	Ι _D T _A = +25°C
0.01 <i>/</i>	2Ω @ V _{GS} = 4V	400mA
60V	2.5Ω @ V _{GS} = 2.5V	350mA

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Power Management Functions
- Battery Operated Systems and Solid-State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.

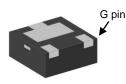
U-DFN1212-3 (Type C)



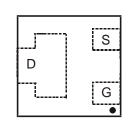
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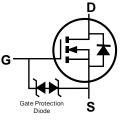
Top View



Bottom View



Pin-Out Top View



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN62D1LFD-7	U-DFN1212-3 (Type C)	3,000/Tape & Reel
DMN62D1LFD-13	U-DFN1212-3 (Type C)	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Low Input Capacitance

Features and Benefits
Low On-Resistance

- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

N-CHANNEL ENHANCEMENT MODE MOSFET

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMN62D1LFDQ</u>)

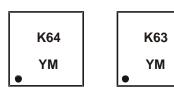
Mechanical Data

- Case: U-DFN1212-3
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e4)
- Terminal Connections: See Diagram
- Weight: 0.005 grams (Approximate)



Marking Information

Site	1	
Onto		•



K64 = Product Type Marking Code K63 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2014		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	В		Н		J	К	L	М	Ν	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code					-	0	-			0	N	-

Site 2:

K64	K63
YWX	YWX
•	•

K64 = Product Type Marking Code	
K63 = Product Type Marking Code	
YWX = Date Code Marking	
Y = Year (ex: 0 = 2020)	
W = Week (ex: a = week 27; z represents week 52 an	d 53)
X = Internal Code (ex: U = Monday)	

Date Code Key

Year	2014		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	4		0	1	2	3	4	5	6	7	8	9
Week	1-26			27-52				53				
Code	A-Z			a-z			Z					
Internal Code	Sur	۱	Mon		Tue	W	ed	Thu		Fri		Sat
Code	Т		U		V	V	V	Х		Y		Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		Vdss	60	V
Gate-Source Voltage		V _{GSS}	±20	V
Continuous Drain Current (Note 5) $V_{GS} = 4V$	T _A = +25°C T _A = +70°C	ID	400 310	mA
Pulsed Drain Current (Note 6)		Ідм	1	А

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Power Dissipation (Note 5)	PD	0.5	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	Reja	237	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

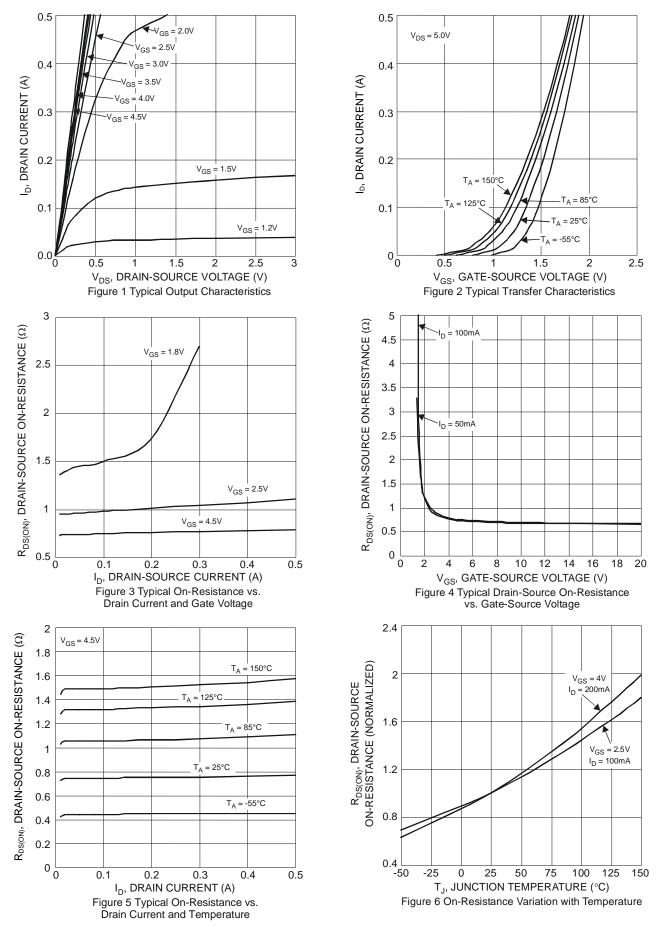
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				•	•	•
Drain-Source Breakdown Voltage	BVDSS	60	_	_	V	Vgs = 0V, Ip = 250µA
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	_	1	μA	VDS = 60V, VGS = 0V
		_	_	±100	nA	$V_{GS} = \pm 5V, V_{DS} = 0V$
Gate-Source Leakage	lgss	_	_	±500	nA	$V_{GS} = \pm 10V, V_{DS} = 0V$
		_	_	±2	μA	$V_{GS} = \pm 15V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.6	_	1	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			0.8	2		$V_{GS} = 4V$, $I_D = 100mA$
Static Drain-Source On-Resistance	Proven		1	2.5	Ω	$V_{GS} = 2.5V, I_{D} = 50mA$
	R _{DS(ON)}		1.4	3		Vgs = 1.8V, ID = 50mA
			1.8			$V_{GS} = 1.5V, I_D = 10mA$
Forward Transfer Admittance	Y _{fs}		1.8	_	S	$V_{DS} = 10V, I_D = 200mA$
Diode Forward Voltage	V _{SD}	_	0.8	1.3	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		36	_		
Output Capacitance	Coss		4.6		pF	$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz
Reverse Transfer Capacitance	Crss		3.6	_		
Gate Resistance	Rg	_	59.8	_	Ω	VDS = 0V, VGS = 0V, f = 1MHz
Total Gate Charge	Qg	_	0.55	_		
Gate-Source Charge	Qgs	_	0.08	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ ID = 250mA
Gate-Drain Charge	Q _{gd}	_	0.12	_		ID = 250IIIA
Turn-On Delay Time	td(ON)		2.1	_	ns	
Turn-On Rise Time	t _R	_	2.8	_	ns	$V_{GS} = 10V, V_{DS} = 30V,$
Turn-Off Delay Time	tD(OFF)		21	—	ns	$R_{L} = 150\Omega, R_{G} = 25\Omega,$ $I_{D} = 200 \text{mA}$
Turn-Off Fall Time	tF		13.9	_	ns	

 Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
Repetitive rating, pulse width limited by junction temperature.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

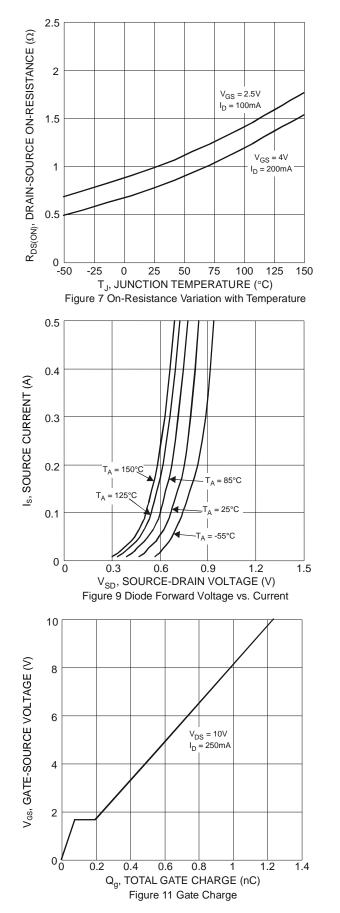


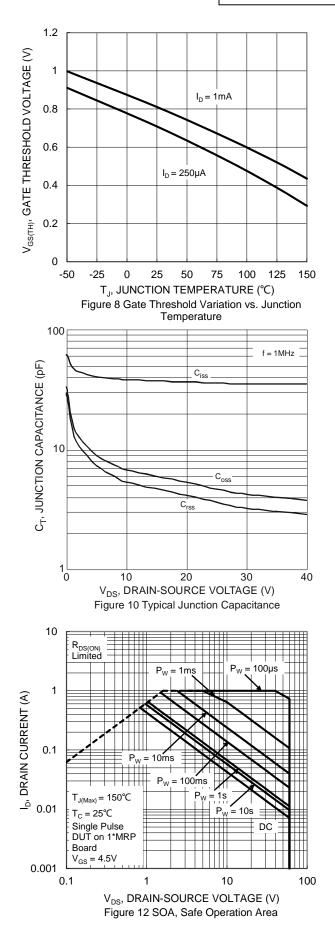
DMN62D1LFD



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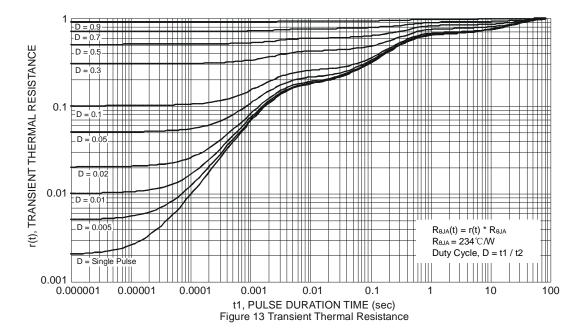








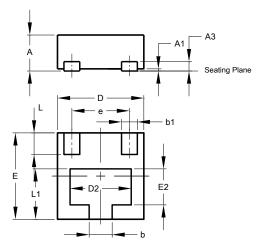






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



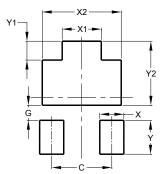
	U-DFN1212-3						
		be C					
Dim	Min	Max	Тур				
Α	0.47	0.53	0.50				
A1	0	0.05	0.02				
A3	-	-	0.13				
b	0.27	0.37	0.32				
b1	0.17	0.27	0.22				
D	1.15	1.25	1.20				
D2	0.75	0.95	0.85				
е	-	-	0.80				
Ε	1.15	1.25	1.20				
E2	0.40	0.60	0.50				
L	0.25	0.35	0.30				
L1	0.65	0.75	0.70				
All	Dimens	sions in	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN1212-3 (Type C)

U-DFN1212-3 (Type C)



Dimensions	Value (in mm)
С	0.800
G	0.200
Х	0.320
X1	0.520
X2	1.050
Y	0.450
Y1	0.250
Y2	0.850

ittp://www.ulodes.com/package-outl



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